



NPN SMALL SIGNAL TRANSISTOR IN SOT23

Features

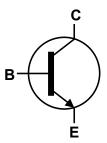
- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856 BC858
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

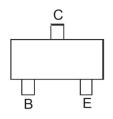
- Case: SOT23
- Case material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

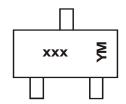
Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC846A-7-F	AEC-Q101	K1Q	7	3,000
BC846AQ-7-F	Automotive	K1Q	7	3,000
BC846B-7-F	AEC-Q101	K1R	7	3,000
BC846BQ-7-F	Automotive	K1R	7	3,000
BC846B-13-F	AEC-Q101	K1R	13	10,000
BC846BQ-13-F	Automotive	K1R	13	10,000
BC847A-7-F	AEC-Q101	K1Q	7	3,000
BC847AQ-7-F	Automotive	K1Q	7	3,000
BC847A-13-F	AEC-Q101	K1Q	13	10,000
BC847B-7-F	AEC-Q101	K1R	7	3,000
BC847BQ-7-F	Automotive	K1R	7	3,000

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC847B-13-F	AEC-Q101	K1R	13	10,000
BC847C-7-F	AEC-Q101	K1M	7	3,000
BC847CQ-7-F	Automotive	K1M	7	3,000
BC847C-13-F	AEC-Q101	K1M	13	10,000
BC848A-7-F	AEC-Q101	K1Q	7	3,000
BC848B-7-F	AEC-Q101	K1R	7	3,000
BC848B-13-F	AEC-Q101	K1R	13	10,000
BC848C-7-F	AEC-Q101	K1M	7	3,000
BC848CQ-7-F	Automotive	K1M	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



xxx = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: Y = 2011) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	Х		Υ	Z		Α	В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	y Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteri	stic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V _{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	$V_{\sf CEO}$	45	V
	BC848		30	
Emitter-Base Voltage	BC846, BC847	\/	6.0	V
Emilier-base voltage	BC848	V _{EBO}	5.0	v
Continuous Collector Current		Ic	100	mA
Peak Collector Current		I _{CM}	200	mA
Peak Emitter Current		I _{EM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	310		mW
	(Note 7)	P _D	350	IIIVV
Thermal Decistance, Junction to Ambient	(Note 6)	0	403	00/14/
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction to Leads (Note 8)		$R_{\theta JL}$	350	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-65 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{6.} For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

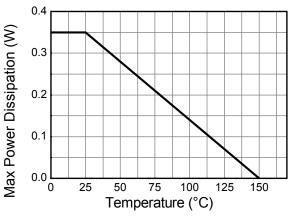
^{7.} Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper.

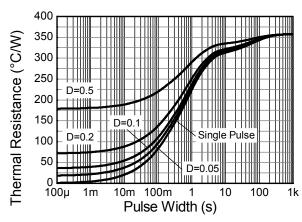
^{8.} Thermal resistance from junction to solder-point (at the end of the leads).

^{9.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



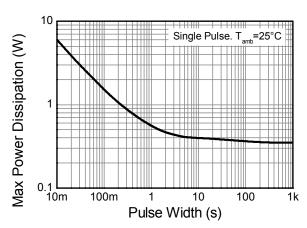
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

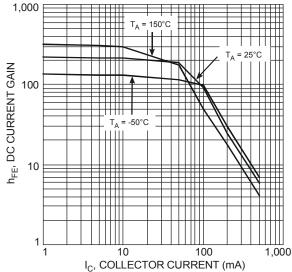
Cha	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC846		80					
Collector-Base Breakdown V	oltage	BC847	BV_CBO	50	_	_	V	$I_C = 10\mu A$	
		BC848		30					
Collector Emitter Breakdown	Collector-Emitter Breakdown Voltage BC8			65					
(Note 10)	voltage	BC847	BV_{CEO}	45	_	_	V	$I_C = 10mA$	
(14010-10)		BC848		30					
Emitter-Base Breakdown Vol	tane	BC846 / BC847	BVFBO	6	_	_	V	I _E = 1μA	
Emilier Base Breakdown voi	tage	BC848	DVEBO	5				,	
Collector Cutoff Current			I _{CBO}	_	_	15	nA	V _{CB} = 30V	
Concotor Cuton Current			ICBO			5	μΑ	$V_{CB} = 30V, T_J = +150^{\circ}C$	
		BC846				15		V _{CE} = 80V	
Collector Emitter Cutoff Curre	ent	BC847	ICES	_	_	15	nA	V _{CE} = 50V	
		BC848				15		V _{CE} = 30V	
Emitter Base Cutoff Current			I _{EBO}	_	_	100	nA	V _{EB} = 5V	
0	BC846A / E	3C847A / BC848A			200				
Small Signal Current Gain (Note 10)	BC846B / E	3C847B / BC848B	h _{fe}	_	330	1 —	_	_	
(Note 10)	BC847	7C / BC848C	1		600				
Input Impedance		3C847A / BC848A			2.7				
(Note 10)	BC846B / BC847B / BC848B	h _{ie}	_	4.5	_	kΩ			
(Note 10)	BC847C / BC848C			8.7			$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$		
Output Admittance		3C847A / BC848A			18			f=1.0kHz	
(Note 10)	BC846B / BC847B / BC848B		h _{oe}	_	30	_	μS		
(11010-10)		7C / BC848C			60			-	
Reverse Voltage Transfer		3C847A / BC848A			1.5x10 ⁻⁴				
Ratio (Note 10)	BC846B / BC847B / BC848B		h _{re}	_	2x10 ⁻⁴	_	_		
		7C / BC848C		110	3x10 ⁻⁴	200			
		3C847A / BC848A	╡.	110	180	220			
DC Current Gain (Note 10)		3C847B / BC848B	h _{FE}	200	290	450	_	$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
		7C / BC848C		420	520	800			
Collector-Emitter Saturation \	/oltage		V _{CE(sat)}	_	90	250	mV	I _C = 10mA, I _B = 0.5mA	
(Note 10)			()		200	600		$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltag	e(Note 10)		V _{BE(on)}	580	660	700	mV	$I_C = 2mA$, $V_{CE} = 5V$	
Badd Emillor Fam on Vollag	0(11010-10)		V BE(UII)	_	_	770	****	$I_C = 10$ mA, $V_{CE} = 5$ V	
Base-Emitter Saturation Voltage(Note 10)		V _{BE(sat)}	_	700		mV	$I_C = 10mA$, $I_B = 0.5mA$		
		V BE(sat)		900		IIIV	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$		
Output Capacitance		C _{obo}	_	3	_	pF	V _{CB} = 10V, f = 1.0MHz		
Transition Frequency		f _T	100	300	_	MHz	V _{CE} = 5V, I _C = 10mA, f = 100MHz		
Noise Figure			NF	_	2	10	dB	V_{CE} =5V, I_{C} =200 μ A R_{S} =2k Ω , f=1kHz Δ f=200Hz	

Note:

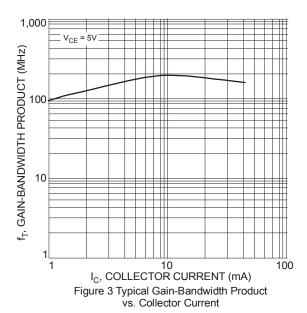
10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

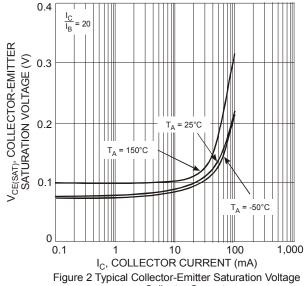


Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



 $I_{C}, \, \text{COLLECTOR} \, \, \text{CURRENT} \, \, (\text{mA})$ Figure 1 Typical DC Current Gain vs. Collector Current



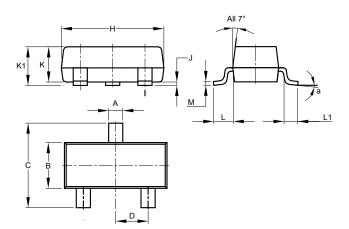


vs. Collector Current



Package Outline Dimensions

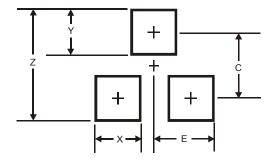
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	8°						
All	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35



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